

Vishay Siliconix

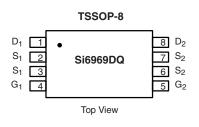
Dual P-Channel 1.8-V (G-S) MOSFET

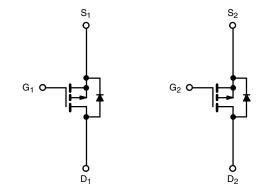
PRODUCT SUMMARY				
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)		
- 12	0.034 at V _{GS} = - 4.5 V	± 4.6		
	0.050 at V _{GS} = - 2.5 V	± 3.8		
	0.075 at V _{GS} = - 1.8 V	± 3.0		

FEATURES

- Halogen-free
- TrenchFET[®] Power MOSFETs: 1.8 V Rated







Ordering Information: Si6969DQ-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	_A = 25 °C, unle	ss otherwise r	noted		
Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	- 12		
Gate-Source Voltage		V _{GS}	± 8	V	
	T _A = 25 °C	- I _D	± 4.6		
Continuous Drain Current $(T_J = 150 \ ^{\circ}C)^{a, b}$	T _A = 70 °C		± 3.8		
Pulsed Drain Current		I _{DM}	± 30	A	
Continuous Source Current (Diode Conduction) ^{a, b}		۱ _S	- 1.25		
Maximum Power Dissipation ^{a, b}	T _A = 25 °C	- P _D	1.1	W	
	T _A = 70 °C		0.72] •••	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum lunction to Ambienta	t ≤ 10 s	R _{thJA}		110	°C/W
Maximum Junction-to-Ambient ^a	Steady State	''thJA	115		C/W

Notes:

a. Surface Mounted on FR4 board.

b. t ≤ 10 s.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 0.45			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 8 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 9.6 V, V _{GS} = 0 V			- 1	μA	
		V_{DS} = - 9.6 V, V_{GS} = 0 V, T_{J} = 70 °C		- 25			
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \geq$ - 8 V, V_{GS} = - 4.5 V	- 30			А	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -4.6 \text{ A}$		0.027	0.034		
		V_{GS} = - 2.5 V, I_D = - 3.8 A		0.037	037 0.050		
		V_{GS} = - 1.8 V, I_D = - 3.0 A		0.053	0.075		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = -8 V, I_{D} = -4.6 A$		18		S	
Diode Forward Voltage ^a	V _{SD}	I _S = - 1.25 A, V _{GS} = 0 V		- 0.68	- 1.1	V	
Dynamic ^b				•			
Total Gate Charge	Qg			21	40	nC	
Gate-Source Charge	Q _{gs}	V_{DS} = - 6 V, V_{GS} = - 4.5 V, I_D = - 4.6 A		4.5			
Gate-Drain Charge	Q _{gd}			3.5			
Turn-On Delay Time	t _{d(on)}			25	50		
Rise Time	t _r	V_{DD} = - 6 V, R_L = 6 Ω		35	60		
Turn-Off Delay Time	t _{d(off)}	I_D \cong - 1 A, V_{GEN} = - 4.5 V, R_G = 6 Ω		80	150	ns	
Fall Time	t _f			40	80		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1.25 A, dl/dt = 100 A/μs		50	100		

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

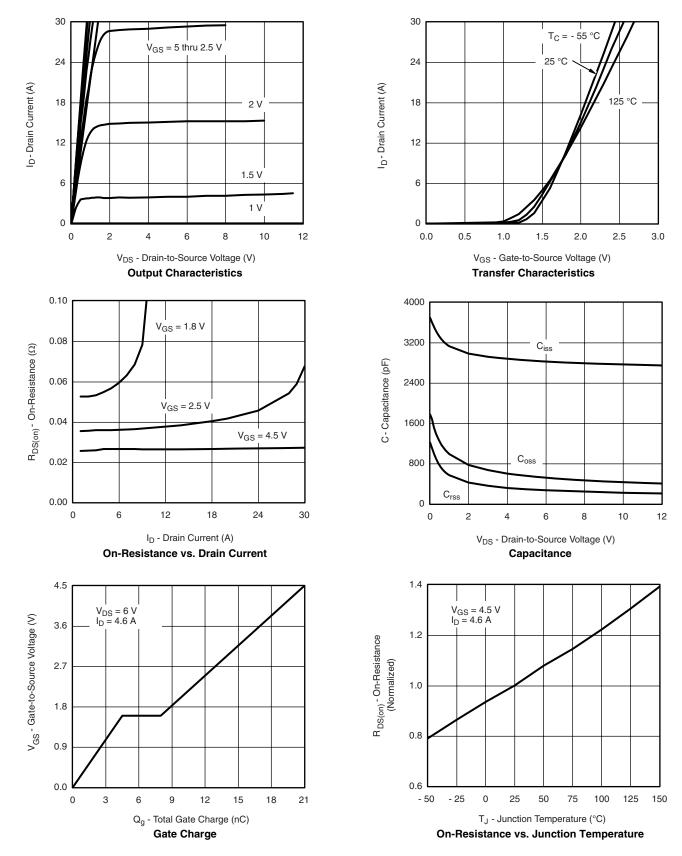
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

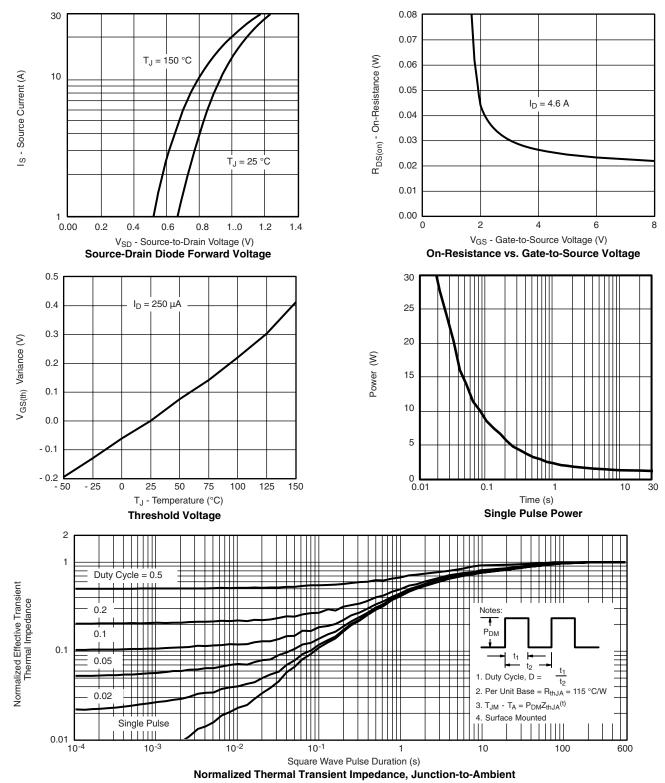


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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see http://www.vishay.com/ppg?70828.

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